

Montag, 13.05.2019 um 15:15 Uhr Ort: Seminarraum 87, Wilhelm Klemm-Straße 10

Site-selectively generated photon emitters in monolayer MoS₂ via helium ion irradiation

Lukas Sigl AG Holleitner / AG Finley / AG Wurstbauer Walter Schottky Institut and TUM Physics Department Garching

Atomically thin TMDCs are well known for their strong light matter interaction and exciton dominated spectral response. Here, we demonstrate the deterministic and site-selective generation of single defect emitters in a monolayer MoS₂ van der Waals heterostructure by bombarding it with a nanometer-focused beam of helium ions. [1] Encapsulation of the defective MoS₂ within hBN greatly enhances the optical quality and reveals narrow spectral lines with emission energies 100-220 meV below the neutral 2D exciton. [2] We spectroscopically investigate single emitters by performing photoluminescence excitation spectroscopy. The emitter line shape reveals a strong asymmetry resembling the interaction with LA/TA phonons. We attribute the emission to atomistic defects induced by the helium ion bombardment and discuss their origin in the light of ab-initio calculations and scanning tunneling microscopy measurements. Finally, we demonstrate the deterministic positioning of optically active defects within the monolayer. We thank the DFG for funding via the cluster of excellence e-conversion.

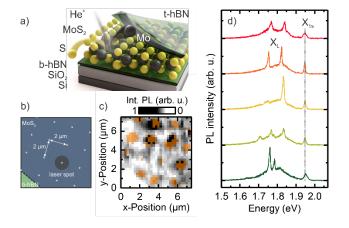


Figure 1: a) Schematic illustration of the exposed MoS₂/hBN van der Waals heterostructure. b) Optical micrograph of a monolayer MoS₂/hBN van der Waals heterostructure. A matrix of 100nm x100nm fields is exposed with a pitch of 2 µm by He lons. c) Corresponding spatially resolved and spectrally integrated PL mapping (grayscale). d) Selected spectra taken from c).

[1] J. Klein et al., 2D Mater. **5**, 1 (2017)

[2] Klein et al., arXiv:1901.01042v2 under review (2019)